



SAMTM Data Sheet SAM-1064-0.6-10ps-x, λ = 1064 nm

 $\lambda = 1064 \text{ nm}$ Laser wavelength

High reflection band $\lambda = 1000 ... 1080 nm$

Absorbance $A_0 = 0.6 \%$ $\Delta R = 0.4 \%$ Modulation depth Non-saturable loss $A_{ns} = 0.2 \%$

 $\Phi_{\text{sat}} = 130 \, \mu \text{J/cm}^2$ Saturation fluence

 $\tau \sim 10 \text{ ps}$ Relaxation time constant

 $\Phi = 3 \text{ mJ/cm}^2$ Damage threshold

Chip area 4.0 mm x 4.0 mm; other dimensions on request

Chip thickness 450 µm

x = FC

Protection the SAM is protected with a dielectric front layer

Mounting option \mathbf{x} denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted x = 12.7 gglued on a gold plated Cu-cylinder with 12.7 mm \varnothing glued on a gold plated Cu-cylinder with 25.4 mm \varnothing x = 25.4 gx = 12.7 ssoldered on a gold plated Cu-cylinder with 12.7 mm \varnothing x = 25.4 ssoldered on a gold plated Cu-cylinder with 25.4 mm Ø x = 25.4 wsoldered on a water cooled Cu-cylinder with 25.4 mm Ø mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance





